

PEMB9

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 47 k Ω

28 December 2022

Product data sheet

1. General description

PNP/PNP double Resistor-Equipped Transistor (RET) in a ultra small flat lead SOT666 Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PEMD9 NPN/NPN complement: PEMH9

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs

3. Applications

- · Low current peripheral driver
- Controlling IC inputs
- · Replaces general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor						
V _{CEO}	collector-emitter voltage	open base	-	-	-50	V
I _O	output current		-	-	-100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	l1	input (base) TR1	6 5 4	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2		R2 R1
6	01	output (collector) TR1	1 2 3	
			SOT666	GND1 I1 O2
				006aaa212

6. Ordering information

Table 3. Ordering information

Type number Package					
	Name	Description	Version		
РЕМВ9	SOT666	plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<u>SOT666</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code
PEMB9	Z6

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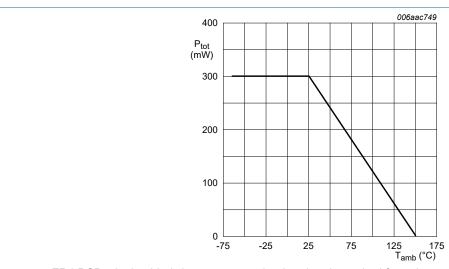
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		•	'	'	
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V _{CEO}	collector-emitter voltage	open base		-	-50	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
VI	input voltage	positive		-	6	V
		negative		-	-40	V
Io	output current			-	-100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	200	mW
Per device	<u> </u>		•	'		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.



FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

Fig. 1. Per device: Power derating curve

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 47 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W
Per device	Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	417	K/W

- [1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.

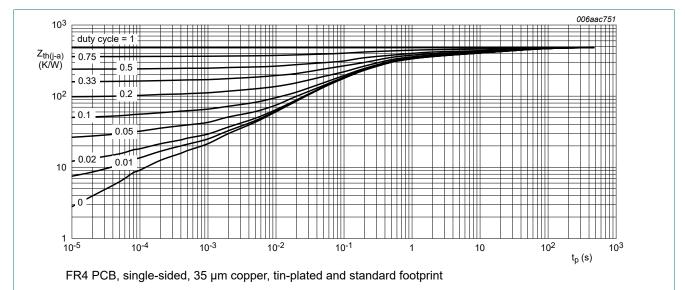


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

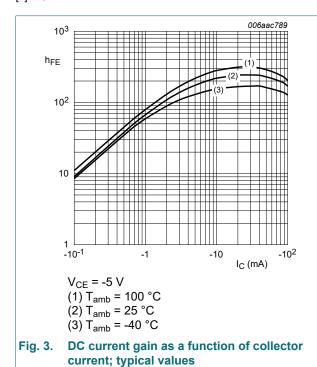
50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 47 k Ω

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or			I			
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 °C$		-50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
I _{CEO} collector-emitter cut-off	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-1	μΑ
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-150	μΑ
h _{FE}	DC current gain	V_{CE} = -5 V; I_{C} = -5 mA; T_{amb} = 25 °C		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	-100	mV
V _{I(off)}	off-state input voltage	V_{CE} = -5 V; I_{C} = -100 μ A; T_{amb} = 25 °C		-	-0.7	-0.5	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -1 mA; T_{amb} = 25 °C		-1.4	-0.8	-	V
R1	bias resistor 1 (input)			7	10	13	kΩ
R2/R1	bias resistor ratio			3.7	4.7	5.7	
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[1]	-	180	-	MHz

[1] Characteristics of built-in transistor



VCEsat (V)

-10-1

-10-2

-10-1

-10-1

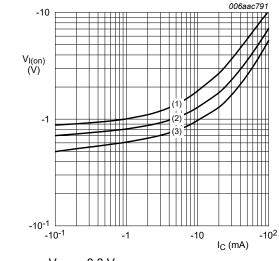
-10-1

-10-2

I_C (mA)

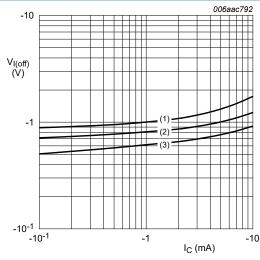
Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 47 k Ω



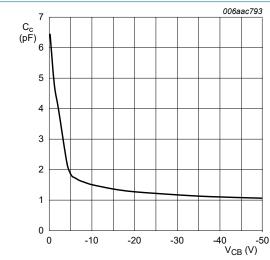
V_{CE} = -0.3 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Fig. 5. On-state input voltage as a function of collector | Fig. 6. current; typical values



V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Off-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$

Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values

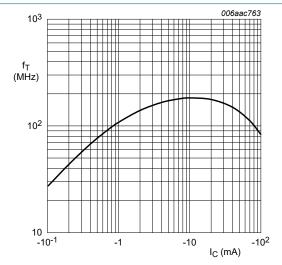


Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

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11. Test information

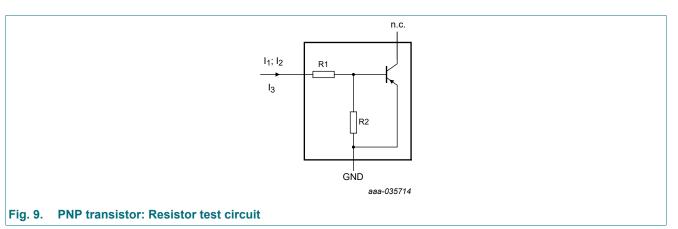
Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I3)}{R1 \cdot I3} - 1$$



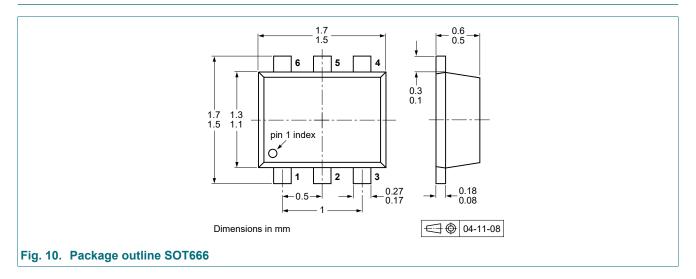
Resistor test conditions

Table 8. Resistor test conditions

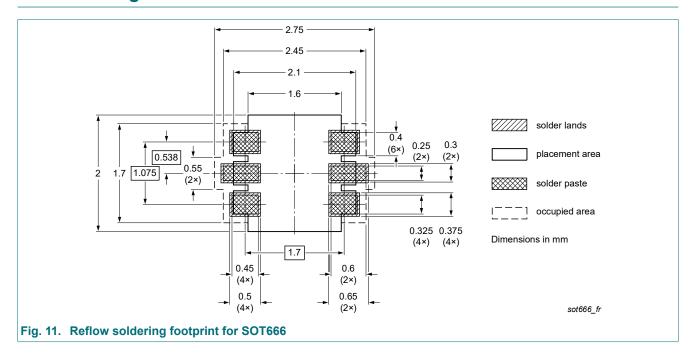
Type number	R1 (kΩ)	R2 (kΩ)	Test conditions		
			I ₁	l ₂	l ₃
PEMB9	10	47	-350 μΑ	-450 μΑ	100 μΑ

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12. Package outline



13. Soldering



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14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PEMB9 v.4	20221228	Product data sheet	-	PEMB9_PUMB9 v.3		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Family data sheet reduced to single type data sheet. Product(s) changed to non-automotive qualification. Packing information is removed. 					
PEMB9_PUMB9 v.3	20111122	Product data sheet	-	PEMB9_PUMB9 v.2		
PEMB9_PUMB9 v.2	20031003	Product data sheet	-	PUMB9 v.1 PEMB9 v.1		
PUMB9 v.1	20030203	Objective specification	-	-		
PEMB9 v.1	20030107	Product specification	-	-		

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50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 47 k Ω

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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